Medium Power Transistor (-60V, -2A)

2SB1561

Features

1) Low saturation voltage, typically VcE(sat) = -0.15V at Ic / Is=-1A / -50mA.

- 2) Collector-emitter voltage = -60 V
- 3) Pc = 2 W

(on 40 x 40 x 0.7 mm ceramic board).

4) Complements the 2SD2391.

●Packaging specifications and hre

| Туре | 2SB1561 |
|------------------------------|---------|
| Package | MPT3 |
| hee | Q |
| Marking | BL* |
| Code | T100 |
| Basic ordering unit (pieces) | 1000 |

^{*} Denotes her

●Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|-----------------------------|--------|-----------------------|------|
| Collector-base voltage | Vсво | -60 | ٧ |
| Collector-emitter voltage | VCEO | -60 | V |
| Emitter-base voltage | VEBQ | -6 | V |
| Collector current | lc | -2 | Α |
| | Ice | -5 | A *1 |
| Collector power dissipation | Pc | 0.5 | w |
| | PC | 2 | *2 |
| Junction temperature | Τj | 150 | ဗ |
| Storage temperature | Tstg | -55~ + 150 | ౮ |

^{*1} Single pulse, Pw=10ms

●Electrical characteristics (Ta=25℃)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
|--------------------------------------|----------|------|-------|-------|------|---------------------------|---|
| Collector-base breakdown voltage | ВУсво | -60 | _ | _ | V | Ic=-50 μ A | |
| Collector-emitter breakdown voltage | BVceo | -60 | _ | _ | ٧ | Ic=-1mA | |
| Emitter-base breakdown voltage | BVEBO | -6 | _ | _ | ٧ | IE=-50 μ A | |
| Collector cutoff current | Ісво | _ | _ | -0.1 | μΑ | V _{CB} =-50V | |
| Emitter cutoff current | lebo | _ | _ | -0.1 | μA | V _{EB} =-5V | |
| Collector-emitter saturation voltage | VCE(sat) | _ | -0.15 | -0.35 | V | Ic/IB=-1A/-50mA | * |
| DC current transfer ratio | hre | 120 | _ | 270 | _ | VcE/Ic=-2V/-0.5A | |
| Transition frequency | fτ | _ | 200 | _ | MHz | Vc=-2V, I==0.5A, f=100MHz | * |
| Output capacitance | Cob | _ | 23 | _ | рF | Vc8=-10V , IE=0A , f=1MHz | |

^{*} Measured using pulse current

(94S-191-B228)

Medium Power Transistor (60V, 2A)

2SD2391

Features

- 1) Low saturation voltage, typically $V_{\text{CE(sat)}} = 0.13V$ at Ic / IB=1A / 50mA.
- 2) Collector-emitter voltage = 60 V
- 3) Pc = 2 W

(on $40\times40\times0.7$ mm ceramic board).

4) Complements the 2SB1561.

●Packaging specifications and hre

| Туре | 2SD2391 |
|------------------------------|---------|
| Package | MPT3 |
| hfE | Q |
| Marking | DT* |
| Code | T100 |
| Basic ordering unit (pieces) | 1000 |

[★] Denotes here

●Absolute maximum ratings (Ta=25℃)

| Parameter | Symbol | Limits | Unit | |
|-----------------------------|--------|----------|---------|--|
| Collector-base voltage | Vcво | 60 | ٧ | |
| Collector-emitter voltage | VCEO | 60 | > | |
| Emitter-base voltage | VEBO | 6 | > | |
| Collector current | lc | 2 | Α | |
| | IC IC | 6 | A *1 | |
| Collector power dissipation | Pc | 0.5 | 187 | |
| | FC | 2 | W *2 | |
| Junction temperature | Tj | 150 | Ç | |
| Storage temperature | Tstg | -55~+150 | ° | |

^{*1} Single pulse, Pw=10ms

●Electrical characteristics (Ta=25°C)

| ` | <u> </u> | | | | | | |
|--------------------------------------|----------|------|------|------|------|------------------------------|---|
| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions | |
| Collector-base breakdown voltage | ВУсво | 60 | _ | _ | V | Ic=50 μ A | |
| Collector-emitter breakdown voltage | BVceo | 60 | _ | _ | ٧ | Ic=1mA | |
| Emitter-base breakdown voltage | ВУево | 6 | _ | _ | ٧ | IE=50 μ A | |
| Collector cutoff current | Ісво | _ | | 0.1 | μΑ | Vc8=50V | |
| Emitter cutoff current | lebo | _ | | 0.1 | μΑ | V _{EB} =5V | |
| Collector-emitter saturation voltage | VCE(sat) | _ | 0.13 | 0.35 | V | Ic/ls=1A/50mA | * |
| DC current transfer ratio | h₅∈ | 120 | _ | 270 | _ | VcE/Ic=2V/0.5A | |
| Transition frequency | fτ | _ | 210 | _ | MHz | Vc=2V , I==-0.5A , f=100MHz* | |
| Output capacitance | Cob | _ | 21 | _ | pF | Vcs=10V, IE=0A, f=1MHz | |

^{*} Measured using pulse current

(94S-380-D228)

^{*2} When mounted on a 40 x 40 x 0.7 mm ceramic board.

^{*2} When mounted on a 40 x 40 x 0.7 mm ceramic board.

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